

PC813 Series

AC Input Response & Nigh Noise Reduction Type Photocoupler

Features

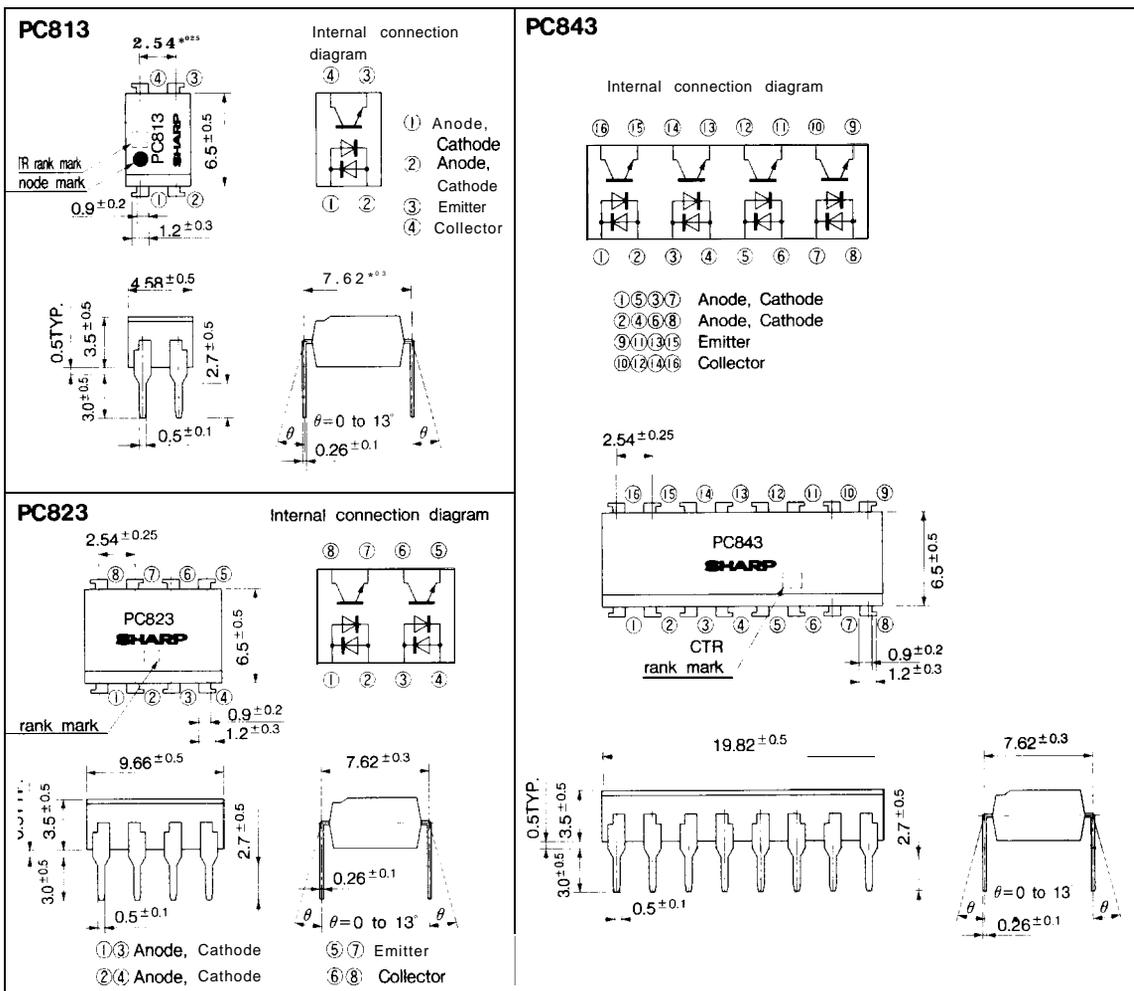
1. High instantaneous common mode rejection voltage (CM_H: TYP.2kV/μs)
2. AC input response
3. Compact dual-in-line package
PC813 (1ch), **PC823** (2ch), **PC843** (4ch)
4. High isolation voltage between input and output (V_{iso}: 5 000 V_{rms})
5. Recognized by UL, file No. E64380

Applications

1. Telephones (PC813)
2. Programmable controllers
(PC823/PC843)
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

Outline Dimensions

(Unit : mm)



6

Photocouplers

***In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device

Absolute Maximum Ratings

(Ta= 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	±50	mA
	*1 Peak forward current	I _{FM}	±1	A
	Power dissipation	P	70	mW
output	Collector -emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	v
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
	Total power dissipation	Plot	200	mW
*Isolation voltage	V _{iso}	5 000	V _{rms}	
Operating temperature	T _{opr}	-30 to + 100	°C	
Storage temperature	T _{strg}	-55 to +125	°C	
*Soldering temperature	T _{sol}	260	°C	

*1 Pulse width ≤ 100^μs, Duty ratio = 0.001

*2 40 to 60%RH, AC for 1 minute

*3 For 10 seconds

Electro-optical Characteristics

(Ta= 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V _F	I _F = ±20mA	—	1.2	1.4	v	
	Peak forward voltage	V _{FM}	I _{FM} = ±0.5A	—	—	3.0	V	
	Terminal capacitance	C _t	V=0, f=1kHz	—	50	250	pF	
output	Collector dark current	I _{CEO}	V _{CE} =20V, I _F =0	—	—	10 ⁻⁷	A	
Transfer characteristics	*4Current transfer ratio	CTR	I _F = ±1mA, V _{CE} =5V	20	—	200	%	
	Collector -emitter saturation voltage	V _{CE(sat)}	I _F = ±20mA, I _C =1mA	—	0.1	0.2	V	
	Isolation voltage	R _{ISO}	DC500V, 40 to 60%RH	5x 10 ¹⁰	10 ¹¹	—	Ω	
	Floating capacitance	C _f	V=0, f=1MHz	—	0.6	1.0	pF	
	Cut -off frequency	f _c	V _{CE} =5V, I _C =2mA, R _L =100Ω	15	—	80	kHz	
	Response time	Rise time	t _r	V _{CE} =2V, I _C =2mA	—	4	18	μs
		Fall time	t _f	R _L =100Ω	—	5	20	μs
*Instantaneous common mode rejection voltage "Output high level"	CM _{HI}	V _{CM} =600V, I _F =0 V _O =2V, R _L =1.9kΩ	—	2	—	kV/μs		
*Instantaneous common mode rejection voltage "Output low level"	CM _{LI}	V _{CM} =600V, I _F =16mA V _O =0.8V.	—	—	—		

*4 Classification table of current transfer ratio is shown below

Model No.	Rank Mark	CTR (%)
PC813A	A	50 to 150%
PC823A		
PC843A		
PC813	A or no mark	20 to 200%
PC823		
PC843		
PC843		

***5 Test Circuit for instantaneous common mode rejection voltage**

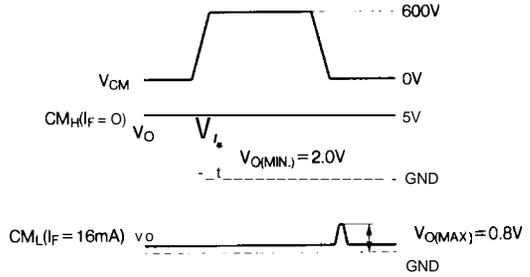
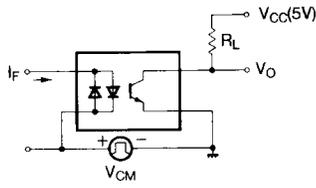


Fig. 1 Forward Current vs. Ambient Temperature

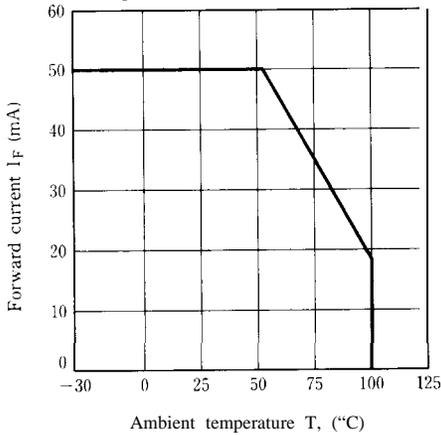


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

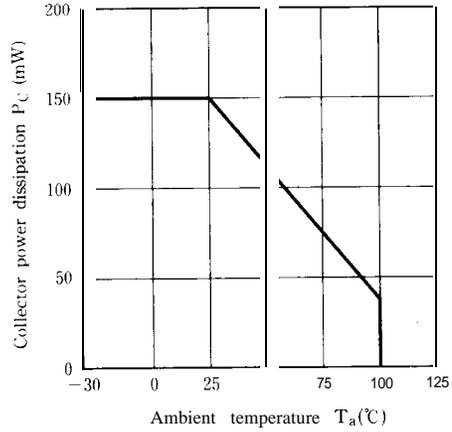


Fig. 3 Peak Forward Current vs. Duty Ratio

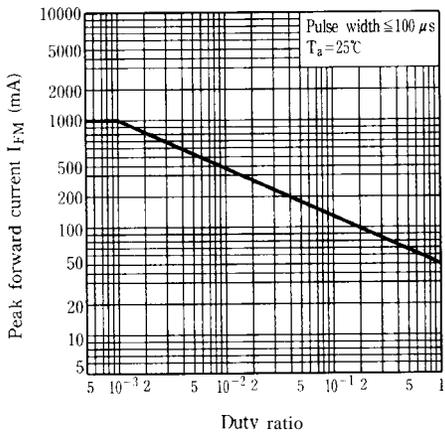


Fig. 4 Forward Current vs. Forward Voltage

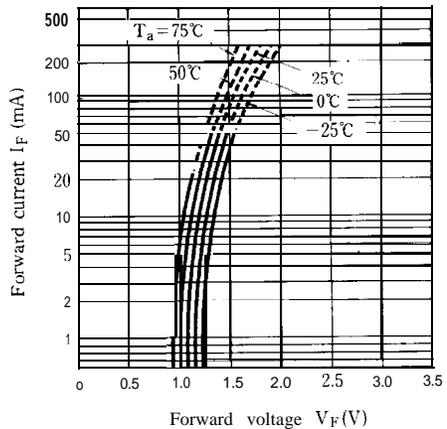


Fig. 5 Current Transfer Ratio vs. Forward Current

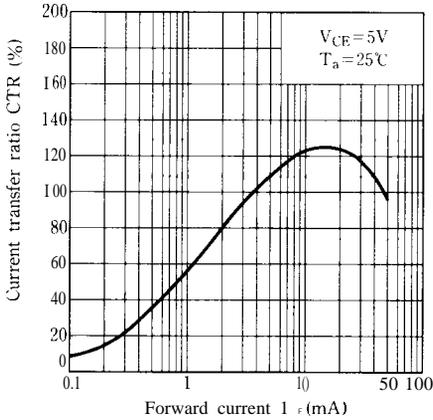


Fig. 6 Collector Current vs. Collector-emitter Voltage

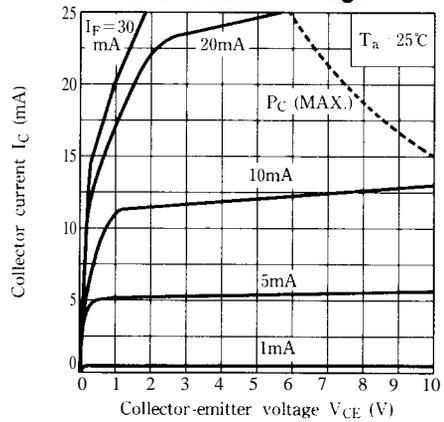


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

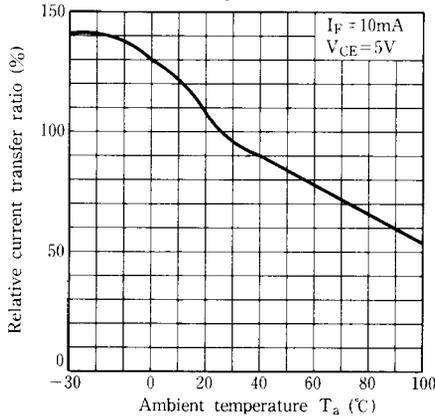


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

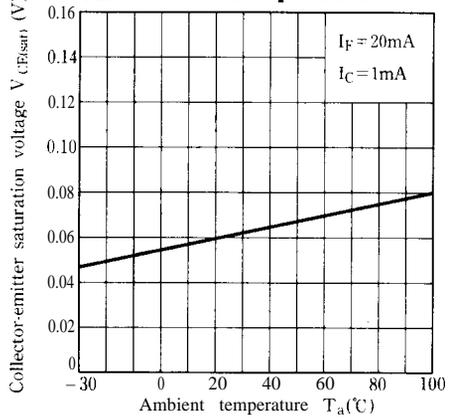


Fig. 9 Collector Dark Current vs. Ambient Temperature

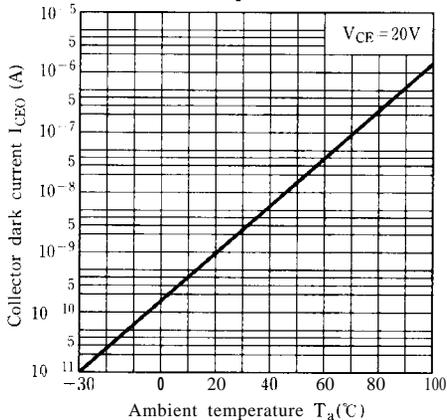


Fig.10 Response Time vs. Load Resistance

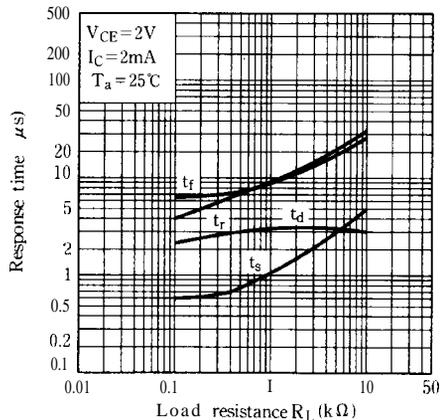
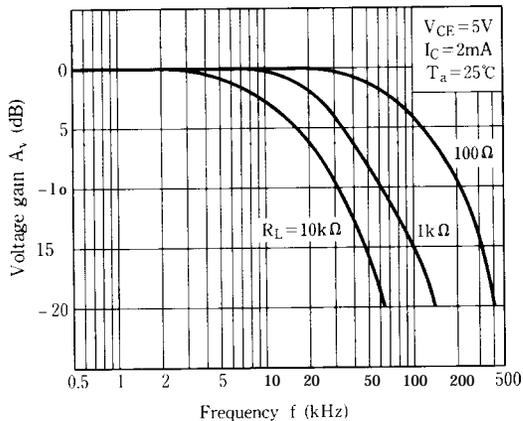


Fig.11 Frequency Response



Test Circuit for Response Time

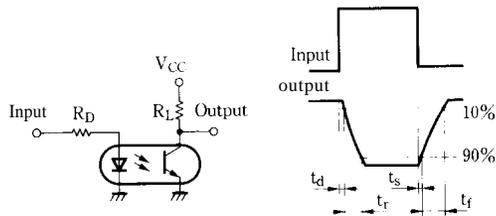
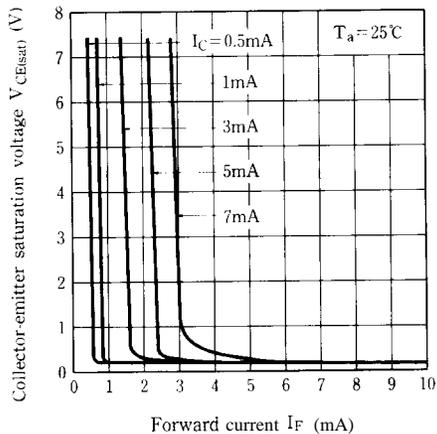
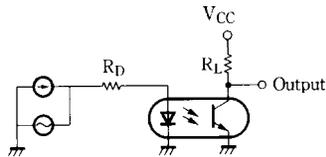


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Frequency Response



● Please refer to the chapter “Precautions for Use” (Page 78 to 93)